

Description

The Flicker-FreeTM IS31LT3935 is a single stage current mode LED driver optimized for high power factor and compatibility with all TRIAC dimmers. The PFC architecture enables excellent power factor over a wide range of operating line and load conditions, even with the simplest of inductor based driver topologies, thereby reducing system cost and size while maximizing efficiency.

The IS31LT3935 LED controller features patent pending AccuDim[™] flicker-free dimming technology that mimics the characteristics of an incandescent light bulb. It presents a dynamic impedance to the dimmer and integrates an active bleed circuit for true dimming performance across all dimmers.

The device is available in a tiny 10 lead DFN-EP (3mm \times 3mm) package. It operates over the temperature range of -40°C to +85°C.

Features

- Smooth 0-100% Flicker-free Dimming Range
- Compatibility with all TRIAC Dimmers (Digital, Leading and Trailing-edge)
- Near unity PFC without External PFC Circuitry
- Spread Spectrum Switching for Reduced EMI
- Low 500µA Quiescent Current
- Protections:
 - Soft Start
 - Under-voltage, (Over-voltage) Lockout
 - Thermal Shutdown

Applications

- Dimmable Retrofit LED Lamps and Luminaries up to 30W
- Industrial and Commercial Lighting
- Offline LED Driver Modules and Bricks

Quick Start

Recommended Equipment

85~265VAC/50~60Hz power supply

- LED array(12 in series)40Vdc-0.37A
- 220V input TRIAC Dimmer

Absolute Maximum Ratings

- ●≤ 264VAC power supply
- ●≤ 47V Vout (Total Vf)

Caution: Do not exceed the conditions listed above, otherwise the board will be damaged or the output will be limited

Procedure

The IS31LT3935 DEMO Board is fully assembled and tested. Follow the steps listed below to verify board operation.

Caution: Do not turn on the power supply until all connections are completed.

- Connect the positive terminal of the LEDs to the LED+ of the DEMO and the negative terminal of the LEDs to the LED- of the Evaluation Board.
- Connect the input pin N of the Evaluation Board via the main power switch to AC power supply N.
- Connect the input pin L of the Evaluation Board via TRAIC Dimmer pin L, Another pin of TRAIC Dimmer Connect to the AC power supply L.
- Turn on the power supply, Adjust the angle of TRAIC Dimmer



Ordering Information

PART#	TEMP RANGE	IC PACKAGE	
	40 to 125°C	DFN-10	
1331L13933-DL32-TR	-40 to 125 C	(Exposed Pad)	

For pricing, delivery, and ordering information, please contact ISSI at analog_mkt@issi.com or call +1-408-969-6600





Note: ISSI Evaluation Board does not include a LED array



Figure 2 Picture of Evaluation Board NOTE: Physical dimensions are (L×W×H): 73mm×25mm×23mm

PCB Layout



Figure 3 PCB Layout - Top layer



Figure 4 PCB Layout - Bottom layer



Bill of Materials

No.	Name	Description	Ref Des.	Qty.	Mfr P/N
1	FUSE	1A250V Φ3	F1	1	
2	MOV	7D471 PIN7	VR	1	
3	Bridge rectifier	DB107 DIP4	BD1	1	
4	Inductor	3mH 0810	L1, L2	2	
5	Inductor	6mH 0810	L3	1	
6	Transformer	450uH PQ2016	TR	1	
7	Resistor	5.1kΩ 5% 0805	R1, R4, R4.1	3	
8	Resistor	510Ω 5% 1W	R2	1	
9	Resistor	200kΩ 1% 1206 R6		1	
10	Resistor	180kΩ 1% 1206 R12		1	
11	Resistor	3.0kΩ 1% 0805	R16	1	
12	Resistor	270kΩ 1% 1206	R7	1	
13	Resistor	200kΩ 1% 1206	R13	1	
14	Resistor	5.6kΩ 1% 0805	R17	1	
15	Resistor	10Ω 1% 1206	R3, R14	2	
16	Resistor	330kΩ 5% 1206	R8	1	
17	Resistor	1.0Ω 5% 0805	R9, R15	1	
18	Resistor	10.0Ω 5% 0805	R15	1	
19	Resistor	100Ω 5% 0805	R10	1	
20	Resistor	5.6M Ω 5% 0805	R11	1	
21	Resistor	NC	R20,R5,C12,C4,R27	0	
22	Resistor	300kΩ 5% 1206	R21,R22	2	
23	Resistor	180kΩ 5% 1206	R23,R24	2	
24	Resistor	180kΩ 1% 0805	R19	1	
25	Resistor	0.16Ω 1% 1206	R18	1	
26	Resistor	200Ω 5% 0805	R26	1	
27	Resistor	51Ω 5% 0805	R25	1	
28	CBB-CAP	68nF 630V pin10	C1	1	
29	CBB-CAP	220nF 630V pin15	C5	1	
30	E-CAP	470uF 50V 1020	C2,C3	2	
31	SMD-CAP	22nF 25V X7R 0805	C6	1	
32	SMD-CAP	1uF 25V X7R 0805	C7,C8	2	
33	SMD-CAP	10uF 25V X7R 0805	C14	1	
34	SMD-CAP	10uF 25V X7R 1206	C9,C10	2	
35	SMD-CAP	33PF 25V X7R 0805	C11	1	
36	SMD-CAP	1nF 1000V X7R 1206	C13	1	
37	Y1-CAP	1nF PIN10	CY	1	
38	SMD-DIODE	ES2J	D1	1	
39	SMD-DIODE	FR107	D6	1	



40	SMD-DIODE	1N914BWT SOD-523F	D2,D4,D5,D7	4
41	SMD-DIODE	1N4148 SOD-80	D10	1
42	SMD-ZENER	9.1V 1% SOD-80	D3	1
43	SMD-ZENER	16V 1% SOD-80	D9	1
44	SMD-ZENER	47V 1% SOD-80	D8	1
45	MOS	4N60C TO-252	Q3	1
46	MOS	AP2306 SOT-23	Q2	1
47	MOS	BSP125 SOT223	Q1	1
48	Photo-coupler	EL357 MSOP-4	U2	1
49	IC	IS31LT3935 DFN10	U1	1
50	CBB-CAP	22nF 630V PIN10	СХ	1

NOTE: please make sure you Dimmer parameter is suitable you application voltage and frequency.





Transformer Design

- ELECTRICAL SPECIFCATIONS:
- 1.Primary inductance(Lp)=450uH@10kHz
- 2. Primary Leakage Inductance (Lk)< = 20uH @10KHz
- 3. Electrical Strength = 3KV, 50/60Hz,1Min

MATERIALS:

- 1. Core:PQ2016(Ferrite Material TDK PC40 or equivalent)
- 2. Bobin:PQ2016 Primary 6,Secondary:8
- 3.. Magnet Wires (Pri) : Type 2-UEW
- 4. Magnet Wire (Sec) : Triple Insulated Wires
- 5. Layer Insulation Tape :3M1298 or equivalent.

SCHEMTIC



NO.	winding	Start	End	number	number	diameter	number of	tape	remar
				of turns	of plies		plies		ks
1	NP1	3	2	17T	2	0.40mm-2-UEW	2	0.02*7.5mm	
2	NS	14	9	16T	2	2P*0.20mm-TEX	3	0.02*7.5mm	
3	NP2	2	1	16T	1	0.40mm- 2-UEW	3	0.02*7.5mm	

Line Regulation and Efficiency

Input Voltage	Input Power	THD	PF	Output Voltage	Output Current	Efficiency
176Vac/50Hz	15.53	11.8%	0.979	40.4	0.329	85.60%
198Vac/50Hz	17.24	13.8%	0.964	40.8	0.360	85.20%
220Vac/50Hz	18.69	26.0%	0.945	41.2	0.386	85.09%
242Vac/50Hz	19.95	27.3%	0.925	41.5	0.407	84.66%
264Vac/50Hz	21.10	28.5%	0.905	41.8	0.424	84.00%

Load Regulation and Efficiency

Input Voltage	Input Power	THD	PF	Output Voltage	Output Current	Efficiency
220Vac/50Hz	18.72	26.1%	0.945	38.14	0.418	85.16%
220Vac/50Hz	18.69	26.0%	0.945	41.2	0.386	85.09%
220Vac/50Hz	18.6	26.0%	0.945	43.9	0.359	84.73%

NOTE: Please don't make the DEMO operation long time without load.



EMI test Report

Organi Place: Detect Limit: Remar	ization: tor: rk:	XM PK+AV EN5501	5		Operat Time: Test-tir Transd	or: ne(ms): luctor:	2013 10 PK0	/4/18/9:31		EUT	:		parameter
Start(M 0.009 0.150 3.000 10.000	/Hz))				End(MI 0.150 3.000 10.000 30.000	Hz)				Step 0.00 0.00 0.02 0.02	(MHz 11 2 20 5)	neq, step
dBu¥													scan resul
120													
100											1 1 1 1 1 1 4 - H- H 1 1 1		
80												·	
60			·	· J - C 4									
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		· ~WP	₩.	W W	¥ "						1 1 1 1 1 1 1 1 1 1 1 1 1 1 1		
0					I I I I						1-FF	1	
0.0 0.009	01 MHz		0.05	0.10		0.50	1.0	0	5.	00	10.0	0 30.	000 MHz
													final test
(AV)	fi O O	req(MHz) 1.104 1.212)		le∨(dBu\ 51.5 47.3	Ŋ		Lim(dBu\ 0.0 54.2	ሳ		∆ 51 -6	.(lev-L .5 .9	im)
	0	.303			43.3			51.6			-8	.4	
	1	.388			42.2			46.0			-3	.8	

EMI TEST REPORT

Figure 5. L line

Organization Place: Detector: Limit: Remark:	n: XM PK+AV EN55015	Operato Time: Test-tim Transdu	r: 2013/4/11 e(ms): 10 ictor: PK0	EUT: 8/9:28	para
Start(MHz) 0.009 0.150 3.000 10.000		End(MH 0.150 3.000 10.000 30.000	z)	Step(N 0.001 0.002 0.020 0.025	/Hz)
dBuV					scan
120					
100					
80			1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1		
60		L			
40		1 materia	the market the	What when the way	han
20	MAN WANT		MM	Marthan	
0		r vw ₩ '			
0.01 0.009 MHz	0.05	0.10	0.50 1.00	5.00 1	0.00 30.000 MH
					final
(AV)	freq(MHz) 0.104 0.203	le∨(dBuV) 57.0 48.5	Lin 0.0 54	n(dBu¥) ⊨ .5	∆(lev-Lim) 57.0 -6.0

EMI TEST REPORT



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a.) the risk of injury or damage has been minimized;

b.) the user assume all such risks; and

c.) potential liability of Integrated Silicon Solution, Inc is adequately protected under the circumst



Modify value of a few components for different output voltage and current application

NO	NO. Ref Des.	Vout=40V lout=0.38A	Vout=33V lout=0.42A	Vout=24V lout=0.65A
	iter Deg.	Description	Description	Description
1	D1	ES2G	ES2G	SB5200
2	C2	470uF 50V	470uF 50V	470uF 35V
3	C3	470uF 50V	470uF 50V	470uF 35V
4	R18	0.16Ω 1% 1206	0.33Ω 1% 1206	0.18Ω 1% 1206
5	R27	NC	0.33Ω 1% 1206	3.0Ω 1% 1206
6	D8	47V 1% SOD-80	39V 1% SOD-80	30V 1% SOD-80

Vout=33V lout=0.42A

Transformer Design

ELECTRICAL SPECIFCATIONS:

- 1.Primary inductance(Lp)=450uH@10kHz
- 2. Primary Leakage Inductance (Lk)< = 20uH @10KHz
- 3. Electrical Strength = 3KV, 50/60Hz,1Min

MATERIALS:

- 1. Core:PQ2016(Ferrite Material TDK PC40 or equivalent)
- 2. Bobin:PQ2016 Primary 6,Secondary:8
- 3.. Magnet Wires (Pri) : Type 2-UEW
- 4. Magnet Wire (Sec) : Triple Insulated Wires
- 5. Layer Insulation Tape :3M1298 or equivalent.

SCHEMTIC



NO.	winding	Start	End	number	number	diameter	number of	tape	remar
				of turns	of plies		plies		ks
1	NP1	3	2	17T	2	0.40mm-2-UEW	2	0.02*7.5mm	
2	NS	14	9	13T	2	0.32mm-TEX	3	0.02*7.5mm	
3	NP2	2	1	16T	1	0.40mm- 2-UEW	3	0.02*7.5mm	



Line Regulation and Efficiency

Input Voltage	Input Power	THD	PF	Output Voltage	Output Current	Efficiency
176Vac/50Hz	14.01	17.1%	0.969	33.74	0.352	84.77%
198Vac/50Hz	15.37	18.9%	0.949	34.09	0.380	84.28%
220Vac/50Hz	16.37	30.8%	0.927	34.37	0.402	84.40%
242Vac/50Hz	17.39	27.3%	0.904	34.60	0.421	83.76%
264Vac/50Hz	18.31	28.5%	0.881	34.81	0.438	83.27%

Load Regulation and Efficiency

Input Voltage	Input Power	THD	PF	Output Voltage	Output Current	Efficiency
220Vac/50Hz	16.38	30.9%	0.926	31.34	0.440	84.19%
220Vac/50Hz	16.37	30.8%	0.927	34.37	0.402	84.40%
220Vac/50Hz	16.43	30.9%	0.926	37.38	0.370	84.73%

NOTE: Please don't make the DEMO operation long time without load.



EMI test Report

Organization Place: Detector: Limit: Remark:	n: XM PK+AV EN55015	Operator: Time: Test-time(m Transducto	LORY CHEN 2013/4/25/14:47 ns): 10 r: PK0	EUT:	paramete
Start(MHz) 0.009 0.150 3.000 10.000		End(MHz) 0.150 3.000 10.000 30.000		Step(MHz) 0.001 0.002 0.020 0.025	freq, step
dBu¥					scan rest
120 100					
80 60					
40 20	MMA	A PAMA			
0	Mar Mar P	M. N		1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	
0.01 0.009 MHz	0.05	0.10 0.	50 1.00	5.00 10.00	30.000 MHz
(AV)	freq(MHz)	le∨(dBuV)	Lim(dBu¥)	Δ(final test lev-Lim)

EMI TEST REPORT

Figure 7. L line



Place:)etector: .imit: &emark:	XM PK+AV EN55015	Oper Time Test- Trans	ator: L : 2 time(ms): 1 sductor: F	ORY CHEN 013/4/25/14:5 0 %0	EUT: 0	
Start(MHz) 1.009 1.150 1.000 0.000		End(1 0.150 3.000 10.00 30.00	MHz) 0		Step(0.001 0.002 0.020 0.025	MHz)
Bu¥						
20						
00						
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	Λ					
	MM. I	MrsA	NAMA	s a weat	Man	man and
0	- MAN		}-\{-\{			
		W				
0.01 .009 MHz	0.05	0.10	0.50	1.00	5.00	10.00 30.000

EMI TEST REPORT

Figure 8. N line



Vout=24V lout=0.64A

Transformer Design

ELECTRICAL SPECIFCATIONS:

- 1.Primary inductance(Lp)=450uH@10kHz
- 2. Primary Leakage Inductance (Lk)< = 20uH @10KHz
- 3. Electrical Strength = 3KV, 50/60Hz,1Min

MATERIALS:

- 1. Core:PQ2016(Ferrite Material TDK PC40 or equivalent)
- 2. Bobin:PQ2016 Primary 6,Secondary:8
- 3.. Magnet Wires (Pri) : Type 2-UEW
- 4. Magnet Wire (Sec) : Triple Insulated Wires
- 5. Layer Insulation Tape :3M1298 or equivalent.

SCHEMTIC



NO.	winding	Start	End	number	number	diameter	number of	tape	remar
				of turns	of plies		plies		ks
1	NP1	3	2	17T	2	0.40mm-2-UEW	2	0.02*7.5mm	
2	NS	14	9	10T	2	0.40mm-TEX	3	0.02*7.5mm	
3	NP2	2	1	16T	1	0.40mm- 2-UEW	3	0.02*7.5mm	

Line Regulation and Efficiency

Input Voltage	Input Power	THD	PF	Output Voltage	Output Current	Efficiency
176Vac/50Hz	14.48	11.5%	0.977	21.81	0.556	83.75%
198Vac/50Hz	16.08	13.4%	0.961	22.17	0.606	83.55%
220Vac/50Hz	17.35	25.5%	0.942	22.45	0.644	83.33%
242Vac/50Hz	18.48	26.8%	0.921	22.67	0.675	82.80%
264Vac/50Hz	19.42	27.8%	0.899	22.85	0.698	82.13%



Load Regulation and Efficiency

Input Voltage	Input Power	THD	PF	Output Voltage	Output Current	Efficiency
220Vac/50Hz	17.25	25.5%	0.941	19.42	0.735	82.75%
220Vac/50Hz	17.35	25.5%	0.942	22.45	0.644	83.33%
220Vac/50Hz	17.25	25.5%	0.941	25.37	0.568	83.54%

NOTE: Please don't make the DEMO operation long time without load.



EMI test Report

Organization: Place: Detector: Limit: Remark:	XM PK+AV EN55015	Operato Time: Test-tim Transdo	or: LORY CHE 2013/4/25/ ne(ms): 10 uctor: PK0	para N EUT: 14:42
Start(MHz) 0.009 0.150 3.000 10.000		End(MH 0.150 3.000 10.000 30.000	lz)	5tep(MHz) 0.001 0.002 0.020 0.025
dBuV				scan
	MMM			
0.01 0.009 MHz	0.05	0.10	0.50 1.00	5.00 10.00 30.000 MH
				final

EMI TEST REPORT

Figure 9. L line

0.0

54.5

52.9

46.3

0.105

0.204

52.9

-8.2





EMI TEST REPORT

Figure 10. N line